



China Compound Semiconductor Standards TC Meeting Agenda

China Winter Standards Meeting

Thursday, December 5th, 2024, 13:00-17:30

Intercontinental Hall 1 of Wuxi Taihu New City Intercontinental Hotel, Jiangsu, China

Time	Topic	Presenter
13:00	Registration	
13:30	Welcome / Call to Order <ul style="list-style-type: none">Opening RemarkIntroductionsMeeting RemindersAgenda Review	Co-chair All SEMI Staff Co-chair
14:00	Review and Approval of Previous Meeting Minutes	SEMI Staff
14:05	SEMI CSM Staff Report	SEMI Staff
14:10	Liaison Reports <ul style="list-style-type: none">Europe CSM CommitteeJapan CM Committee	SEMI Staff SEMI Staff
14:20	TF Reports <ul style="list-style-type: none">Silicon Carbide Substrate Task ForceSiC Epitaxial Wafer Task ForceGaN Task Force	Jiaqi ZHANG - Perfect Crystal Gan FENG -Epiworld Guoqiao TAO -Enkris
14:35	Documents Request for Ballots <ul style="list-style-type: none">Doc. 6769, New Standard: Test Method for Residual Stress of Silicon Carbide Wafers by Photoelastic	Jiaqi ZHANG - Perfect Crystal
15:45	New SNARF Application <ul style="list-style-type: none">New Standard: Specification of Multiple Materials Substrate for GaN Epitaxial Growth Aiming at HB-LEDNew Standard: Specification of High Purity Silicon Carbide Powder for SiC Substrate	Neng ZHANG - Sinopatt Yiqi PENG -Linton
16:45	New Action Items & Update	
16:55	Next Meeting Date & Locale	
17:00	Group Photo	
17:10	Core Member Application and Renew	
17:30	Adjournment	
18:00	Welcome Dinner	